

Features

- Temperature Ranges:
 - Industrial: -40 °C to 85 °C
 - Automotive-A: -40 °C to 85 °C
- Pin and Function Compatible with CY7C1021B
- High Speed
 - $t_{AA} = 10$ ns
- Low Active Power
 - $I_{CC} = 80$ mA at 10 ns
- Low CMOS Standby Power
 - $I_{SB2} = 3$ mA
- 2.0 V Data Retention
- Automatic Power Down when Deselected
- CMOS for Optimum Speed and Power
- Independent Control of Upper and Lower Bits
- Available in Pb-free 44-pin 400-Mil Wide Molded SOJ and 44-pin TSOP II Packages

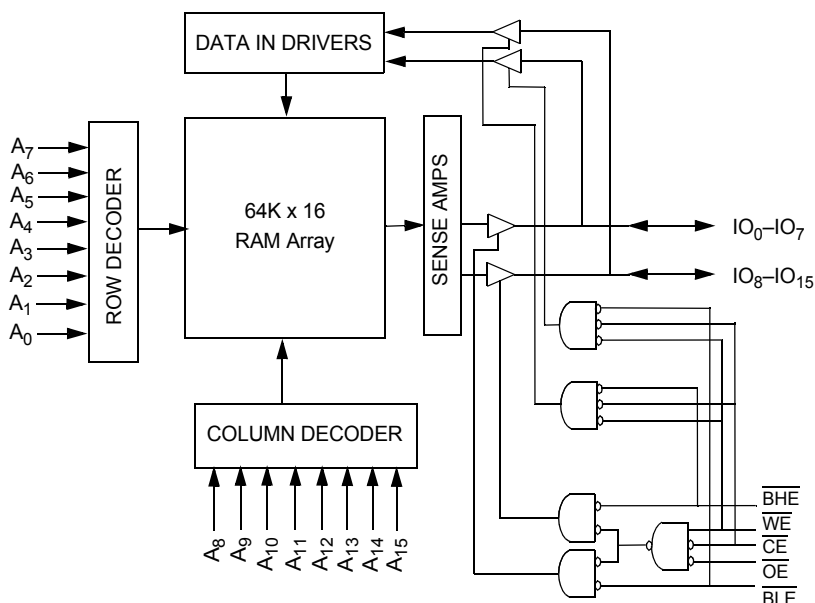
Functional Description

The CY7C1021D is a high performance CMOS static RAM organized as 65,536 words by 16 bits. This device has an automatic power down feature that significantly reduces power consumption when deselected. The input and output pins (IO_0 through IO_{15}) are placed in a high impedance state when the device is deselected ($\overline{CE}$ HIGH), outputs are disabled ($\overline{OE}$ HIGH), BHE and $\overline{BLE}$ are disabled (BHE , $\overline{BLE}$ HIGH), or during a write operation ($\overline{CE}$ LOW and $\overline{WE}$ LOW).

Write to the device by taking Chip Enable ($\overline{CE}$) and Write Enable ($\overline{WE}$) inputs LOW. If Byte Low Enable ($\overline{BLE}$) is LOW, then data from I/O pins (IO_0 through IO_7), is written into the location specified on the address pins (A_0 through A_{15}). If Byte High Enable (BHE) is LOW, then data from I/O pins (IO_8 through IO_{15}) is written into the location specified on the address pins (A_0 through A_{15}).

Read from the device by taking Chip Enable ($\overline{CE}$) and Output Enable ($\overline{OE}$) LOW while forcing the Write Enable ($\overline{WE}$) HIGH. If Byte Low Enable ($\overline{BLE}$) is LOW, then data from the memory location specified by the address pins appears on IO_0 to IO_7 . If Byte High Enable (BHE) is LOW, then data from memory appears on IO_8 to IO_{15} . See the Truth Table on page 10 for a complete description of read and write modes.

Logic Block Diagram



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Pin Configuration

Figure 1. 44-pin SOJ / 44-pin TSOP II (Top View) ^[1]

A ₄	1	44	A ₅
A ₃	2	43	A ₆
A ₂	3	42	A ₇
A ₁	4	41	$\overline{\text{OE}}$
A ₀	5	40	$\overline{\text{BHE}}$
$\overline{\text{CE}}$	6	39	$\overline{\text{BLE}}$
IO ₀	7	38	IO ₁₅
IO ₁	8	37	IO ₁₄
IO ₂	9	36	IO ₁₃
IO ₃	10	35	IO ₁₂
V _{CC}	11	34	V _{SS}
V _{SS}	12	33	V _{CC}
IO ₄	13	32	IO ₁₁
IO ₅	14	31	IO ₁₀
IO ₆	15	30	IO ₉
IO ₇	16	29	IO ₈
$\overline{\text{WE}}$	17	28	NC
A ₁₅	18	27	A ₈
A ₁₄	19	26	A ₉
A ₁₃	20	25	A ₁₀
A ₁₂	21	24	A ₁₁
NC	22	23	NC

Selection Guide

Description	-10 (Industrial / Automotive-A)	Unit
Maximum Access Time	10	ns
Maximum Operating Current	80	mA
Maximum CMOS Standby Current	3	mA

Note

1. NC pins are not connected on the die.

Maximum Ratings

Exceeding the maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage Temperature -65 °C to +150 °C

Ambient Temperature with
Power Applied -55 °C to +125 °C

Supply Voltage on
 V_{CC} to Relative GND^[2] -0.5 V to +6.0 V

DC Voltage Applied to Outputs
in High Z State ^[2] -0.5 V to $V_{CC} + 0.5$ V

DC Input Voltage ^[2] -0.5 V to $V_{CC} + 0.5$ V

Current into Outputs (LOW) 20 mA

Static Discharge Voltage
(per MIL-STD-883, Method 3015) > 2001 V

Latch Up Current > 200 mA

Operating Range

Range	Ambient Temperature	V_{CC}	Speed
Industrial	-40 °C to +85 °C	5 V $\pm$ 10%	10 ns
Automotive-A			

Electrical Characteristics

Over the Operating Range

Parameter	Description	Test Conditions		-10 (Industrial / Automotive-A)		Unit
				Min	Max	
V _{OH}	Output HIGH Voltage	I _{OH} = −4.0 mA		2.4	–	V
V _{OL}	Output LOW Voltage	I _{OL} = 8.0 mA		–	0.4	V
V _{IH}	Input HIGH Voltage			2.2	V _{CC} + 0.5 V	V
V _{IL}	Input LOW Voltage ^[2]			−0.5	0.8	V
I _{IX}	Input Leakage Current	GND ≤ V _I ≤ V _{CC}		−1	+1	μA
I _{OZ}	Output Leakage Current	GND ≤ V _I ≤ V _{CC} , Output Disabled		−1	+1	μA
I _{CC}	V _{CC} Operating Supply Current	V _{CC} = Max, I _{OUT} = 0 mA, f = f _{max} = 1/t _{RC}	100 MHz	–	80	mA
			83 MHz	–	72	mA
			66 MHz	–	58	mA
			40 MHz	–	37	mA
I _{SB1}	Automatic CE Power Down Current – TTL Inputs	Max V _{CC} , $\overline{CE} \geq V_{IH}$, V _{IN} ≥ V _{IH} or V _{IN} ≤ V _{IL} , f = f _{max}		–	10	mA
I _{SB2}	Automatic CE Power Down Current – CMOS Inputs	Max V _{CC} , $\overline{CE} \geq V_{CC} - 0.3$ V, V _{IN} ≥ V _{CC} − 0.3 V, or V _{IN} ≤ 0.3 V, f = 0		–	3	mA

Note

2. $V_{IL}(\text{min}) = -2.0$ V and $V_{IH}(\text{max}) = V_{CC} + 1$ V for pulse durations of less than 5 ns.

Capacitance

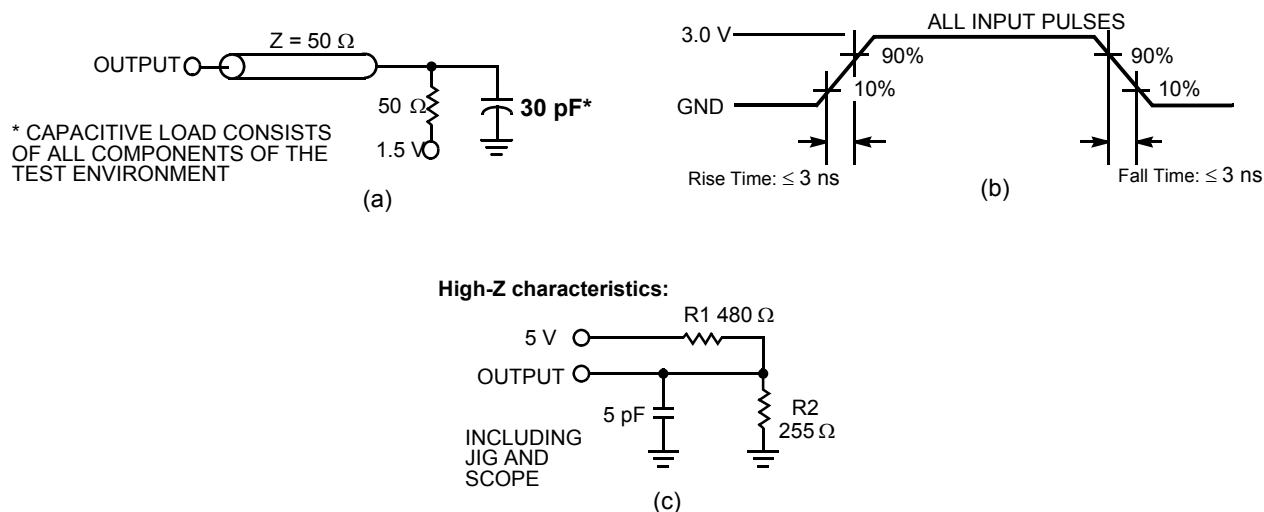
Parameter ^[3]	Description	Test Conditions	Max	Unit
C_{IN}	Input capacitance	$T_A = 25^\circ\text{C}$, $f = 1\text{ MHz}$, $V_{CC} = 5.0\text{ V}$	8	pF
C_{OUT}	Output capacitance		8	pF

Thermal Resistance

Parameter ^[3]	Description	Test Conditions	44-pin SOJ	44-pin TSOP II	Unit
Θ_{JA}	Thermal resistance (junction to ambient)	Still Air, soldered on a 3×4.5 inch, four-layer printed circuit board	59.52	53.91	$^\circ\text{C/W}$
Θ_{JC}	Thermal resistance (junction to case)		36.75	21.24	$^\circ\text{C/W}$

AC Test Loads and Waveforms

Figure 2. AC Test Loads and Waveforms ^[4]



Notes

- Tested initially and after any design or process changes that may affect these parameters.
- AC characteristics (except High Z) are tested using the load conditions shown in Figure 2 (a). High Z characteristics are tested for all speeds using the test load shown in Figure 2 (c).

Switching Characteristics

Over the Operating Range

Parameter ^[5]	Description	-10 (Industrial / Automotive-A)		Unit
		Min	Max	
Read Cycle				
t _{power} ^[6]	V _{CC} (typical) to the first access	100	–	μs
t _{RC}	Read Cycle Time	10	–	ns
t _{AA}	Address to Data Valid	–	10	ns
t _{OHA}	Data Hold from Address Change	3	–	ns
t _{ACE}	$\overline{\text{CE}}$ LOW to Data Valid	–	10	ns
t _{DOE}	$\overline{\text{OE}}$ LOW to Data Valid	–	5	ns
t _{LZOE}	$\overline{\text{OE}}$ LOW to Low Z ^[7]	0	–	ns
t _{HZOE}	$\overline{\text{OE}}$ HIGH to High Z ^[7, 8]	–	5	ns
t _{LZCE}	$\overline{\text{CE}}$ LOW to Low Z ^[7]	3	–	ns
t _{HZCE}	$\overline{\text{CE}}$ HIGH to High Z ^[7, 8]	–	5	ns
t _{PU}	$\overline{\text{CE}}$ LOW to Power-Up	0	–	ns
t _{PD}	$\overline{\text{CE}}$ HIGH to Power-Down	–	10	ns
t _{DBE}	Byte Enable to Data Valid	–	5	ns
t _{LZBE}	Byte Enable to Low Z	0	–	ns
t _{HZBE}	Byte Disable to High Z	–	5	ns
Write Cycle ^[9]				
t _{WC}	Write Cycle Time	10	–	ns
t _{SCE}	$\overline{\text{CE}}$ LOW to Write End	7	–	ns
t _{AW}	Address Setup to Write End	7	–	ns
t _{HA}	Address Hold from Write End	0	–	ns
t _{SA}	Address Setup to Write Start	0	–	ns
t _{PWE}	$\overline{\text{WE}}$ Pulse Width	7	–	ns
t _{SD}	Data Setup to Write End	6	–	ns
t _{HD}	Data Hold from Write End	0	–	ns
t _{LZWE}	$\overline{\text{WE}}$ HIGH to Low Z ^[7]	3	–	ns
t _{HZWE}	$\overline{\text{WE}}$ LOW to High Z ^[7, 8]	–	5	ns
t _{BW}	Byte Enable to End of Write	7	–	ns

Notes

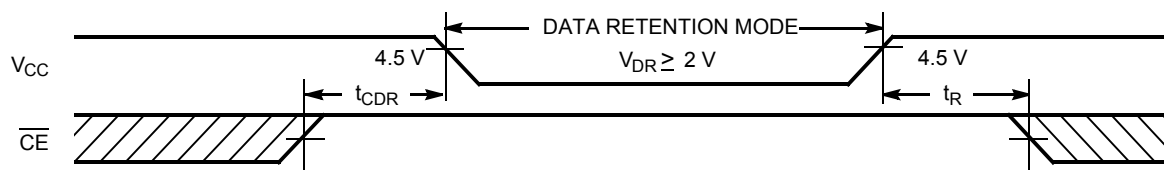
- Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and output loading of the specified $I_{\text{OL}}/I_{\text{OH}}$ and 30-pF load capacitance.
- t_{POWER} gives the minimum amount of time that the power supply should be at typical V_{CC} values until the first memory access can be performed.
- At any given temperature and voltage condition, t_{HZOE} is less than t_{LZCE} , t_{HZOE} is less than t_{LZOE} , and t_{HZWE} is less than t_{LZWE} for any given device.
- t_{HZOE} , t_{HZBE} , t_{HZCE} , and t_{HZWE} are specified with a load capacitance of 5 pF as in (c) of [Figure 2 on page 5](#). Transition is measured when the outputs enter a high impedance state.
- The internal write time of the memory is defined by the overlap of $\overline{\text{CE}}$ LOW, $\overline{\text{WE}}$ LOW and $\overline{\text{BHE}}/\overline{\text{BLE}}$ LOW. $\overline{\text{CE}}$, $\overline{\text{WE}}$ and $\overline{\text{BHE}}/\overline{\text{BLE}}$ must be LOW to initiate a write, and the transition of these signals can terminate the write. The input data setup and hold timing should be referenced to the leading edge of the signal that terminates the write.

Data Retention Characteristics

Over the Operating Range

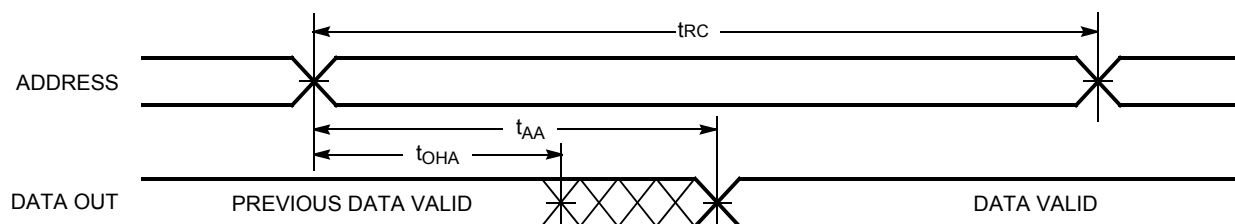
Parameter	Description	Conditions	Min	Max	Unit
V_{DR}	V_{CC} for Data Retention		2.0	–	V
I_{CCDR}	Data Retention Current	$V_{CC} = V_{DR} = 2.0\text{ V}$, $\overline{CE} \geq V_{CC} - 0.3\text{ V}$, $V_{IN} \geq V_{CC} - 0.3\text{ V}$ or $V_{IN} \leq 0.3\text{ V}$	–	3	mA
$t_{CDR}^{[10]}$	Chip Deselect to Data Retention Time		0	–	ns
$t_R^{[11]}$	Operation Recovery Time		t_{RC}	–	ns

Data Retention Waveform



Switching Waveforms

Figure 3. Read Cycle No. 1 (Address Transition Controlled) [12, 13]

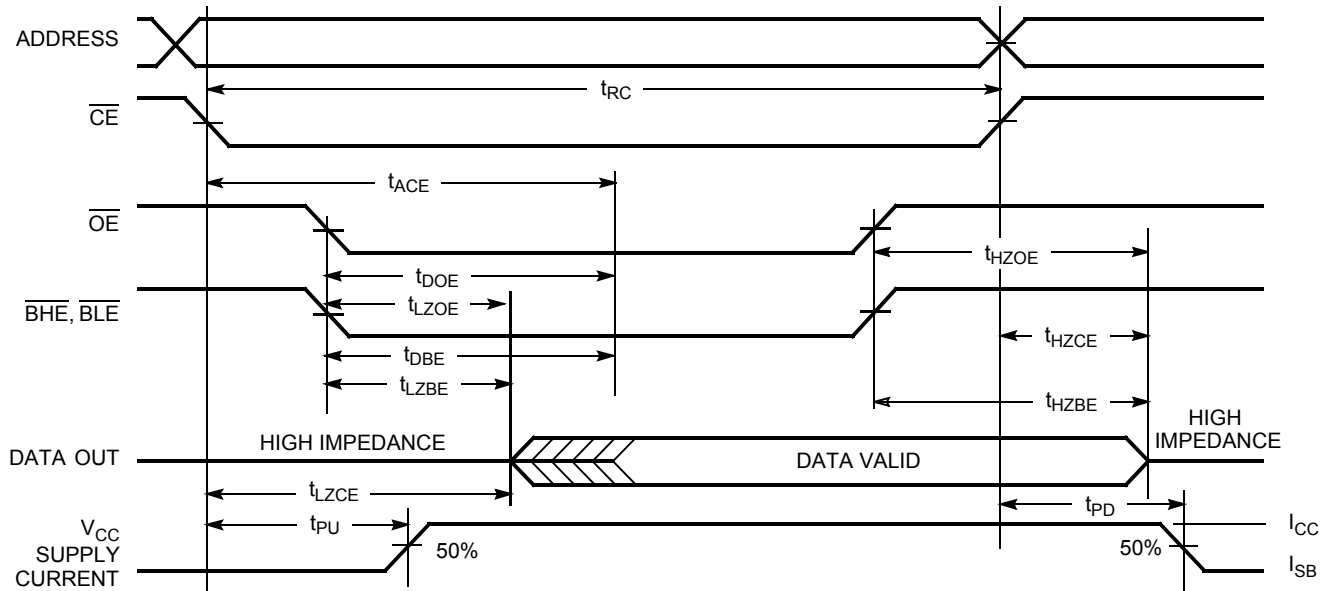


Notes

10. $V_{IL}(\text{min}) = -2.0\text{ V}$ and $V_{IH}(\text{max}) = V_{CC} + 1\text{ V}$ for pulse durations of less than 5 ns.
11. Full device operation requires linear V_{CC} ramp from V_{DR} to $V_{CC}(\text{min}) \geq 50\text{ }\mu\text{s}$ or stable at $V_{CC}(\text{min}) \geq 50\text{ }\mu\text{s}$.
12. Device is continuously selected. OE, CE, BHE and/or BLE = V_{IL} .
13. WE is HIGH for read cycle.

Switching Waveforms (continued)

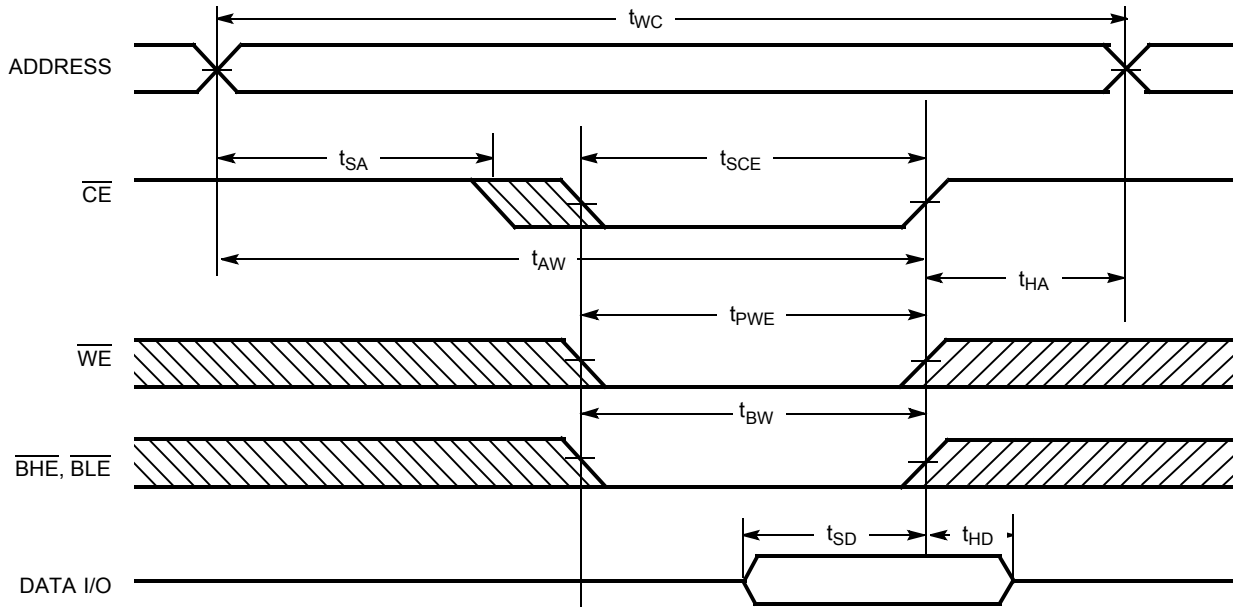
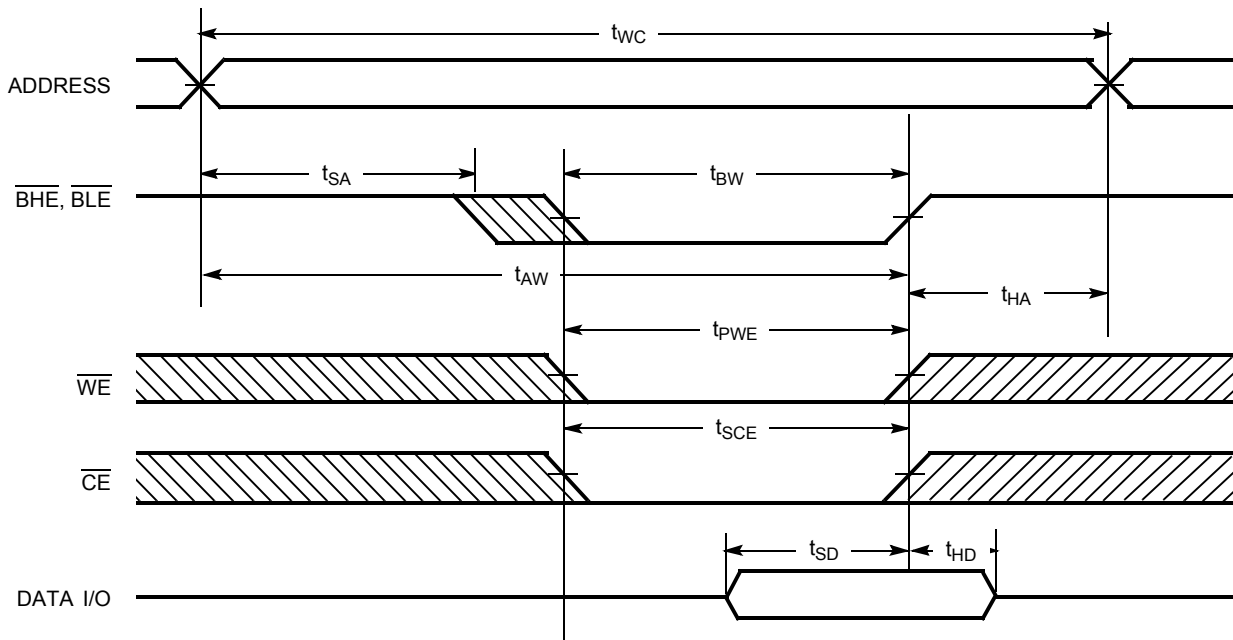
Figure 4. Read Cycle No. 2 ($\overline{OE}$ Controlled) [14, 15]



Notes

- 14. $\overline{WE}$ is HIGH for read cycle.
- 15. Address valid prior to or coincident with $\overline{CE}$ transition LOW.

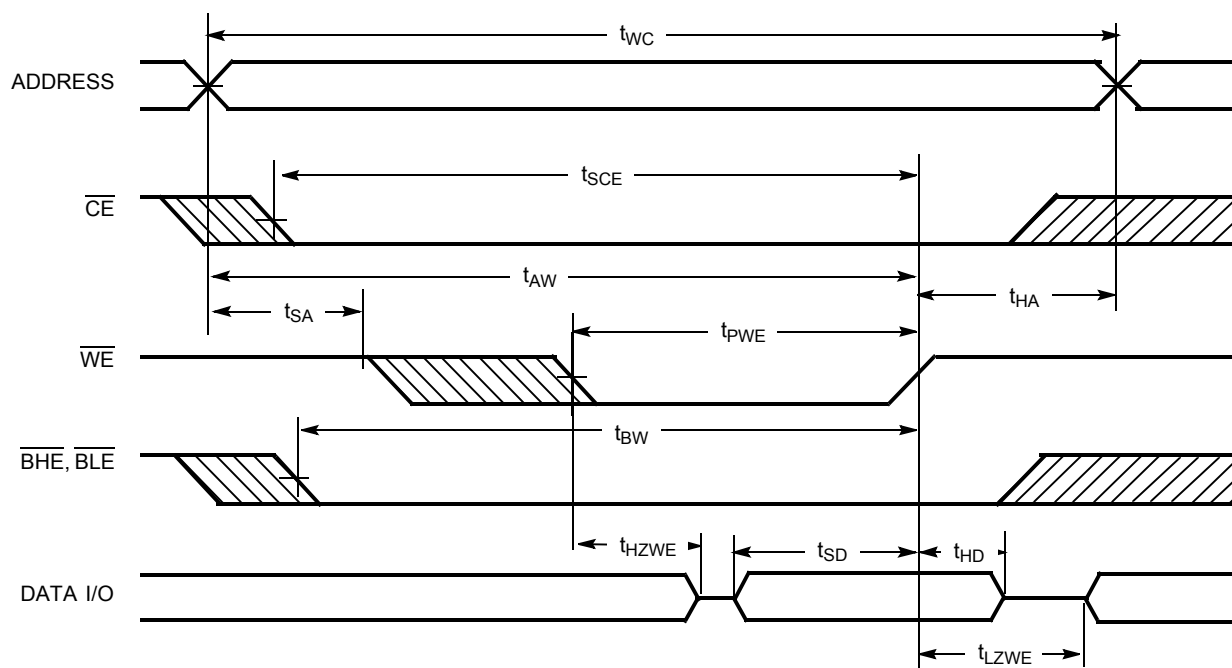
Switching Waveforms (continued)

Figure 5. Write Cycle No. 1 ($\overline{\text{CE}}$ Controlled) [16, 17]

Figure 6. Write Cycle No. 2 ($\overline{\text{BLE}}$ or $\overline{\text{BHE}}$ Controlled)

Notes

 16. Data I/O is high impedance if $\overline{\text{OE}}$ or $\overline{\text{BHE}}$ and/or $\overline{\text{BLE}} = V_{IH}$.

 17. If $\overline{\text{CE}}$ goes HIGH simultaneously with $\overline{\text{WE}}$ going HIGH, the output remains in a high impedance state.

Switching Waveforms (continued)

Figure 7. Write Cycle No. 3 ($\overline{WE}$ Controlled, $\overline{OE}$ LOW)

Truth Table

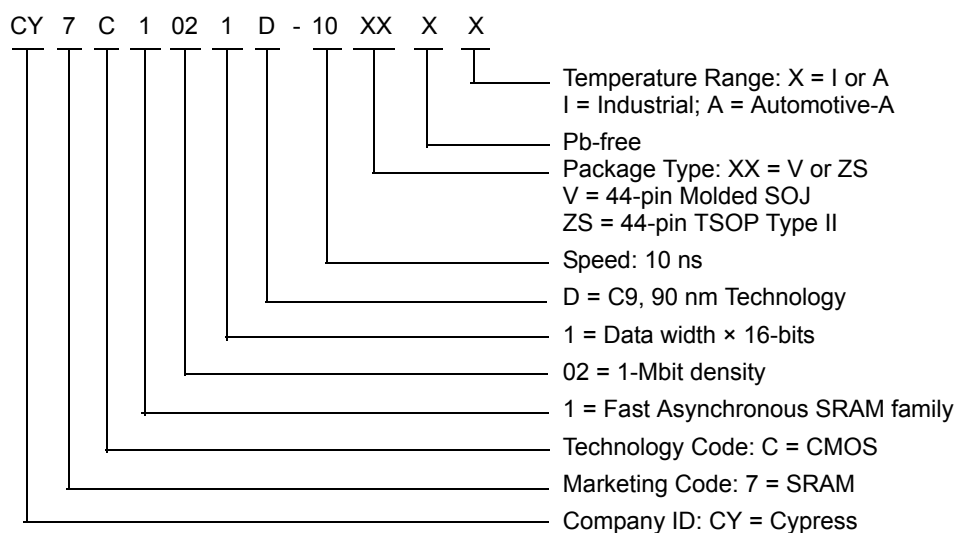
$\overline{CE}$	$\overline{OE}$	$\overline{WE}$	$\overline{BLE}$	$\overline{BHE}$	IO_0-IO_7	IO_8-IO_{15}	Mode	Power
H	X	X	X	X	High Z	High Z	Power Down	Standby (I_{SB})
L	L	H	L	L	Data Out	Data Out	Read – All bits	Active (I_{CC})
			L	H	Data Out	High Z	Read – Lower bits only	Active (I_{CC})
			H	L	High Z	Data Out	Read – Upper bits only	Active (I_{CC})
L	X	L	L	L	Data In	Data In	Write – All bits	Active (I_{CC})
			L	H	Data In	High Z	Write – Lower bits only	Active (I_{CC})
			H	L	High Z	Data In	Write – Upper bits only	Active (I_{CC})
L	H	H	X	X	High Z	High Z	Selected, Outputs Disabled	Active (I_{CC})
L	X	X	H	H	High Z	High Z	Selected, Outputs Disabled	Active (I_{CC})

Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
10	CY7C1021D-10VXI	51-85082	44-pin (400-Mil) Molded SOJ (Pb-free)	Industrial
	CY7C1021D-10ZSXI	51-85087	44-pin TSOP Type II (Pb-free)	
	CY7C1021D-10ZSXA			Automotive-A

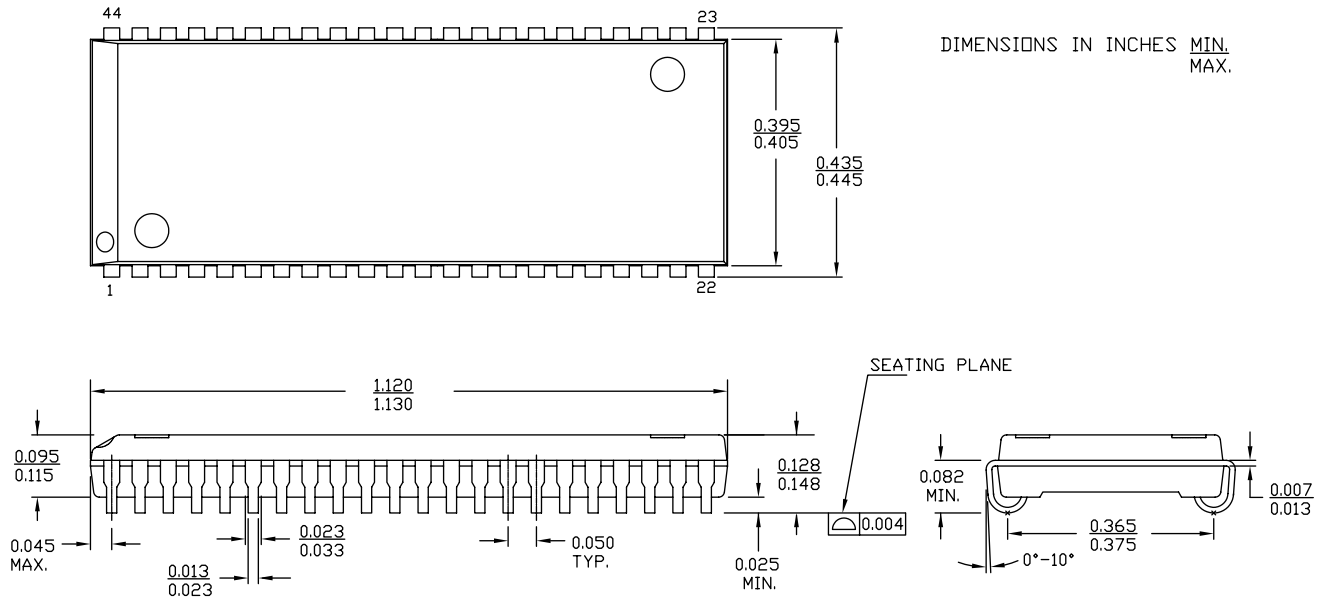
Shaded areas contain advance information. Contact your local Cypress sales representative for availability of these parts.

Ordering Code Definitions



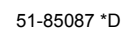
Package Diagrams

Figure 8. 44-pin SOJ (400 Mils) V44.4 Package Outline, 51-85082



51-85082 *D

Figure 9. 44-pin TSOP Z44-II Package Outline, 51-85087



Acronyms

Acronym	Description
$\overline{\text{CE}}$	chip enable
CMOS	complementary metal oxide semiconductor
I/O	input/output
$\overline{\text{OE}}$	output enable
SOJ	small outline J-lead
SRAM	static random access memory
TSOP	thin small outline package
TTL	transistor-transistor logic
$\overline{\text{WE}}$	write enable

Document Conventions

Units of Measure

Symbol	Unit of Measure
°C	degree Celsius
MHz	megahertz
μA	microampere
μs	microsecond
mA	milliampere
mm	millimeter
ms	millisecond
ns	nanosecond
Ω	ohm
%	percent
pF	picofarad
V	volt
W	watt

Document History Page

Document Title: CY7C1021D, 1-Mbit (64 K × 16) Static RAM Document Number: 38-05462				
Rev.	ECN No.	Orig. of Change	Submission Date	Description of Change
**	201560	SWI	See ECN	Advance Information data sheet for C9 IPP
*A	233695	RKF	See ECN	DC parameters modified as per EROS (Spec # 01-02165) Pb-free Offering in the Ordering Information
*B	263769	RKF	See ECN	Added Data Retention Characteristics Table Added T _{power} Spec in Switching Characteristics Table Shaded Ordering Information
*C	307601	RKF	See ECN	Reduced Speed bins to –10 and –12 ns
*D	520647	VKN	See ECN	Changed status from Preliminary to Final. Removed Commercial Operating range Added I _{CC} values for the frequencies 83MHz, 66MHz and 40MHz Updated Thermal Resistance table Added Automotive Product Information Updated Ordering Information Table Changed Overshoot spec from V _{CC} +2V to V _{CC} +1V in footnote #4
*E	802877	VKN	See ECN	Changed Commercial operating range I _{CC} spec from 60 mA to 80 mA for 100MHz, 55 mA to 72 mA for 83MHz, 45 mA to 58 mA for 66MHz, 30 mA to 37 mA for 40MHz Changed Automotive operating range I _{CC} spec from 100 mA to 120 mA for 83MHz, 90 mA to 100 mA for 66MHz, 60 mA to 63 mA for 40MHz
*F	2751755	VKN / PYRS	08/14/09	For 12 ns speed, changed I _{CC} spec from 120 mA to 90 mA For 12 ns speed, changed I _{SB1} spec from 50 mA to 10 mA and I _{SB2} spec from 15 mA to 10 mA
*G	2898399	AJU	03/24/2010	Updated Package Diagrams .
*H	3109897	AJU	12/14/2010	Added Ordering Code Definitions .
*I	3245199	PRAS	04/30/2011	Dislodged Automotive information to new datasheet (001-68372). Removed the Note “Automotive Product Information is Preliminary.” in page 3. Added Acronyms and Units of Measure . Updated in new template.
*J	3086499	AJU	06/07/2011	Updated Functional Description (Removed “For best practice recommendations, refer to the Cypress application note AN1064, SRAM System Guidelines.”).
*K	3540685	TAVA / AJU	03/06/2012	Updated Features (Included Automotive-A Range information). Updated Selection Guide (Included Automotive-A Range information). Updated Operating Range (Included Automotive-A Range information). Updated Electrical Characteristics (Included Automotive-A Range information). Updated Switching Characteristics (Included Automotive-A Range information). Updated Ordering Information (included the part number CY7C1021D-10ZSXA). Updated Package Diagrams .

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кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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